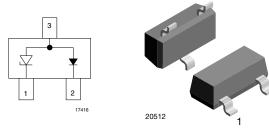
# GL05T to GL24T

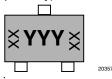
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#### **MARKING** (example only)



Bar = cathode marking

YYY = type code (see table below) XX = date code

DESIGN SUPPORT TOOLS click logo to get started



### **FEATURES**

- IEC 61000-4-5 (lightning) see I<sub>PPM</sub> below
- ESD immunity acc. IEC 61000-4-2 ± 8 kV contact discharge ± 15 kV air discharge
- ESD capability according to AEC-Q101: human body model: class H3B: > 8 kV
- SOT-23 package
- High temperature soldering guaranteed: 260 °C/10 s at terminals
- · Low capacitance for high speed data lines, cellular handsets, USB port protection, LAN equipment, peripherals
- e3 Sn
- AEC-Q101 qualified available
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

ORDERING INFORMATION								
	ENVIR	ONMENTAL AN	ID QUALITY C	ODE	PACKAG	ING CODE		
PART NUMBER (EXAMPLE)	AEC-Q101 QUALIFIED	RoHS-CON LEAD (P		TIN PLATED	3K PER 7" REEL (8 mm TAPE),	10K PER 13" REEL (8 mm TAPE),	ORDERING CODE (EXAMPLE)	
	STANDARD GREEN PLATED 15K/BOX = MO	15K/BOX = MOQ	10K/BOX = MOQ					
GL05T-		E		3	-08		GL05T-E3-08	
GL05T-			G	3	-08		GL05T-G3-08	
GL05T-	Н	E		3	-08		GL05T-HE3-08	
GL05T-	Н		G	3	-08		GL05T-HG3-08	
GL05T-		E		3		-18	GL05T-E3-18	
GL05T-			G	3		-18	GL05T-G3-18	
GL05T-	Н	E		3		-18	GL05T-HE3-18	
GL05T-	Н		G	3		-18	GL05T-HG3-18	

PACK	AGE DAT	Ά					
DEVICE NAME	PACKAGE NAME	TYPE CODE	ENVIRONMENTAL STATUS	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
GL05T	SOT-23	L05	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GLUUT	301-23	L06	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GL12T	SOT-23	L12	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GETZT	301-23	L13	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GL15T	SOT-23	L15	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GEIGI	301-23	L16	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GL24T	SOT-23	L24	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GL241	501-25	L25	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

Rev. 2.2, 03-May-17

For technical questions, contact: ESDprotection@vishay.com

Document Number: 85809





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1



ABSOLUTE MAXIMU	IM RATINGS GL05	т			
PARAMETER	TEST	CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I <sub>PPM</sub>	25	А
Peak pulse power	8/20 µs waveform	Fin 1-2 (pin 3 n.c.)	P <sub>PP</sub>	300	W
	Contact discharge	acc. IEC 61000-4-2; 10 pulses	M	± 8	kV
ESD immunity	Air discharge acc.	EC 61000-4-2; 10 pulses	V <sub>ESD</sub>	± 15	kV
Blocking voltage	I <sub>B</sub> = 1 μA	Pin 2-1 or pin 2-3	VB	70	V
Operating temperature	Junction temperatu	ire	TJ	-55 to +150	°C
Storage temperature			T <sub>STG</sub>	-55 to +150	°C

ABSOLUTE MAXIMU	M RATINGS GL12	т			
PARAMETER	TEST	TEST CONDITIONS		VALUE	UNIT
Peak pulse current	8/20 μs	Pin 1-2 (pin 3 n.c.)	I <sub>PPM</sub>	12	А
Peak pulse power	8/20 µs waveform	Fin 1-2 (pin 3 n.c.)	P <sub>PP</sub>	300	W
ESD immunity	Contact discharge	acc. IEC 61000-4-2; 10 pulses	M	± 8	kV
	Air discharge acc. I	EC 61000-4-2; 10 pulses	V <sub>ESD</sub>	± 8 ± 15	kV
Blocking voltage	I <sub>B</sub> = 1 μA	Pin 2-1 or pin 2-3	VB	70	V
Operating temperature	Junction temperatu	ire	TJ	-55 to +150	°C
Storage temperature			T <sub>STG</sub>	-55 to +150	°C

ABSOLUTE MAXIMU	M RATINGS GL15	т			
PARAMETER	TEST	TEST CONDITIONS		VALUE	UNIT
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I <sub>PPM</sub>	10	А
Peak pulse power	8/20 µs waveform	Fin 1-2 (pin 3 n.c.)	P <sub>PP</sub>	300	W
ESD immunity	Contact discharge a	acc. IEC 61000-4-2; 10 pulses	V	± 8	kV
ESD minunity	Air discharge acc. I	EC 61000-4-2; 10 pulses	V <sub>ESD</sub>	± 15	kV
Blocking voltage	I <sub>B</sub> = 1 μΑ	Pin 2-1 or pin 2-3	VB	70	V
Operating temperature	Junction temperatu	re	TJ	-55 to +150	°C
Storage temperature			T <sub>STG</sub>	-55 to +150	°C

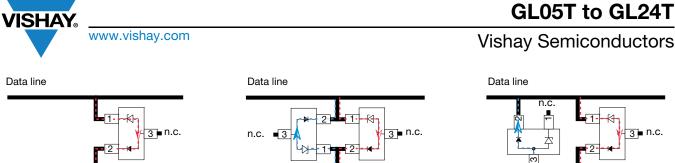
ABSOLUTE MAXIMU	M RATINGS GL24	т			
PARAMETER	TEST	TEST CONDITIONS		VALUE	UNIT
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I <sub>PPM</sub>	5	А
Peak pulse power	8/20 µs waveform	Fin 1-2 (pin 3 n.c.)	P <sub>PP</sub>	300	W
	Contact discharge a	acc. IEC 61000-4-2; 10 pulses	M	± 8	kV
ESD immunity	Air discharge acc. I	EC 61000-4-2; 10 pulses	V <sub>ESD</sub>	5 300	kV
Blocking voltage	I <sub>B</sub> = 1 μΑ	Pin 2-1 or pin 2-3	VB	70	V
Operating temperature	Junction temperatu	re	TJ	-55 to +150	°C
Storage temperature			T <sub>STG</sub>	-55 to +150	°C

The GLxxT contains an avalanche diode (pin 3-1) and a switching diode (pin 3-2). With pin 1 connected to the signal or data line and pin 2 connected to ground both diodes are in series (pin 3 remains unconnected). The big and robust avalanche diode, driven in reverse direction, provides the working range V<sub>BWM</sub> of 5 V, 12 V, 15 V or 24 V. Due to its size the capacitance of the avalanche diode is in the range of typ. 260 pF (GL05T) and 65 pF (GL24T). The small switching diode in series has a low capacitance of just 2.5 pF (typ.). As both diodes are in series (with pin 3 not connected) the total capacitance of both diodes measured between pin 1 and 2 is as low as the capacitance of the switching diode.

Before the GLxxT can provide this low capacitance the big capacitance of the avalanche diode has to be charged up with the first signal or data pulses. This is usually no problem for digital signals like USB or other data ports.

With the GLxxT a signal or data line can be protected against positive transients only. For negative transients another GLxxT can be used to provide a back path for the negative transients as well.

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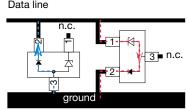




ground



clamping performance for positive and negative transients.



BiAs Bidirectional and Asymmetrical clamping performance for positive and negative transients.

<b>ELECTRICAL CHARACTERISTICS GL05T</b> ( $T_{amb} = 25$ °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	V <sub>RWM</sub>	-	-	5	V		
Reverse voltage	at I <sub>R</sub> = 20 μA	V <sub>R</sub>	5	-	-	V		
Reverse current	at V <sub>R</sub> = 5 V	I <sub>R</sub>	-	-	20	μA		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	6.9	7.5	8.0	V		
Boverne elemping veltage	at I <sub>PP</sub> = 1 A	V	-	-	9.8	V		
Reverse clamping voltage	at I <sub>PP</sub> = 5 A	V <sub>C</sub>	-	-	11	V		
Capacitance	at $V_R = 0 V$ ; f = 1 MHz	CD	-	2.5	5	pF		

### ELECTRICAL CHARACTERISTICS GL12T (T<sub>amb</sub> = 25 °C unless otherwise specified) pin 1 to pin 2: pin 3 not connected

	eenneeted					
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines
Reverse stand-off voltage	Max. reverse working voltage	V <sub>RWM</sub>	-	-	12	V
Reverse voltage	at I <sub>R</sub> = 1 μA	V <sub>R</sub>	12	-	-	V
Reverse current	at V <sub>R</sub> = 12 V	I <sub>R</sub>	-	-	1	μA
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	13.3	14.3	17.2	V
Powerse elemping veltage	at I <sub>PP</sub> = 1 A	V	-	-	19	V
Reverse clamping voltage	at I <sub>PP</sub> = 5 A	V <sub>C</sub>	-	-	24	V
Capacitance	at $V_R = 0 V$ ; f = 1 MHz	CD	-	2.5	5	pF

<b>ELECTRICAL CHARACTERISTICS GL15T</b> (T <sub>amb</sub> = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	V <sub>RWM</sub>	-	-	15	V		
Reverse voltage	at I <sub>R</sub> = 1 μA	V <sub>R</sub>	15	-	-	V		
Reverse current	at V <sub>R</sub> = 15 V	I <sub>R</sub>	-	-	1	μA		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	16.7	17.7	22	V		
Powerse elemping veltage	at I <sub>PP</sub> = 1 A	V	-	-	24	V		
Reverse clamping voltage	at I <sub>PP</sub> = 5 A	V <sub>C</sub>	-	-	33	V		
Capacitance	at $V_R = 0 V$ ; f = 1 MHz	CD	-	2.5	5	pF		



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<b>ELECTRICAL CHARACTERISTICS GL24T</b> (T <sub>amb</sub> = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	V <sub>RWM</sub>	-	-	24	V		
Reverse voltage	at I <sub>R</sub> = 1 μA	V <sub>R</sub>	24	-	-	V		
Reverse current	at V <sub>R</sub> = 24 V	I <sub>R</sub>	-	-	1	μA		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	26.7	28.2	33	V		
	at I <sub>PP</sub> = 1 A	V	-	-	43	V		
Reverse clamping voltage	at I <sub>PP</sub> = 5 A	V <sub>C</sub>	-	-	55	V		
Capacitance	at $V_R = 0$ V; f = 1 MHz	CD	-	2.5	5	pF		

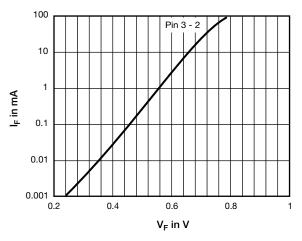


Fig. 1 - Typical Forward Current  $I_{\text{F}}$  vs. Forward Voltage  $V_{\text{F}}$ 

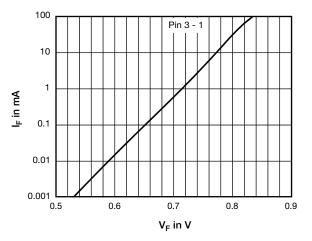


Fig. 2 - Typical Forward Current I<sub>F</sub> vs. Forward Voltage V<sub>F</sub>

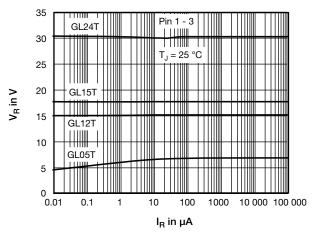
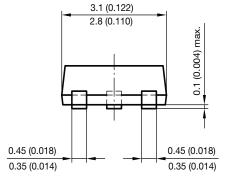


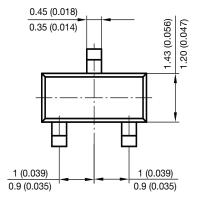
Fig. 3 - Typical Reverse Voltage  $V_{\mathsf{R}}$  vs. Reverse Current  $\mathsf{I}_{\mathsf{R}}$ 

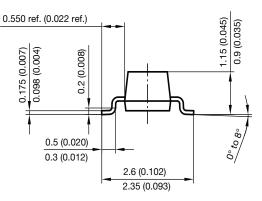
### **Vishay Semiconductors**

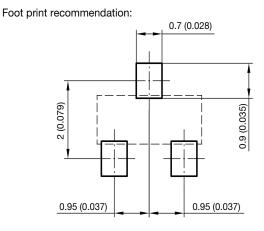


### PACKAGE DIMENSIONS in millimeters (inches): SOT-23



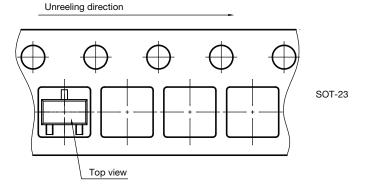






Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23.Sept.2009 17418

Orientation in carrier tape SOT-23 S8-V-3929.01-006 (4) 04.02.2010 22607



5

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